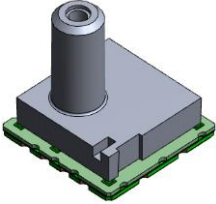


## Digital Output Micro Pressure Sensor

## MMR920C04 Data Sheet

### DESCRIPTION



The MMR920C04 digitally outputs a micro pressure value which was corrected. Customers need no correction because it corrects and outputs the differences of sensors and temperature characteristics. It does not require complicated sensor drive or control circuit, and devices with high performance can be made only with this module and an external microcontroller which will be the host.

### FEATURES

- Small package: 7.0(W) × 7.0(D) × 7.2(H)mm  
Operating pressure range -40~+40cmH<sub>2</sub>O(-3.922~+3.922kPa)  
Effective resolution: 0.002 cmH<sub>2</sub>O<sub>RMS</sub> (0.2Pa<sub>RMS</sub>) (at MODE4)  
Pressure measurement error: ±0.5[%FS]
- It corrects the differences of sensors and temperature characteristics when shipped from our factory.
- It digitally outputs pressure value corrected in the module. (SPI/I<sup>2</sup>C)  
I<sup>2</sup>C slave address (7 bits) is 0x67
- Noise reduction is possible by a built-in Low Pass Filter.

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BLOCK DIAGRAM

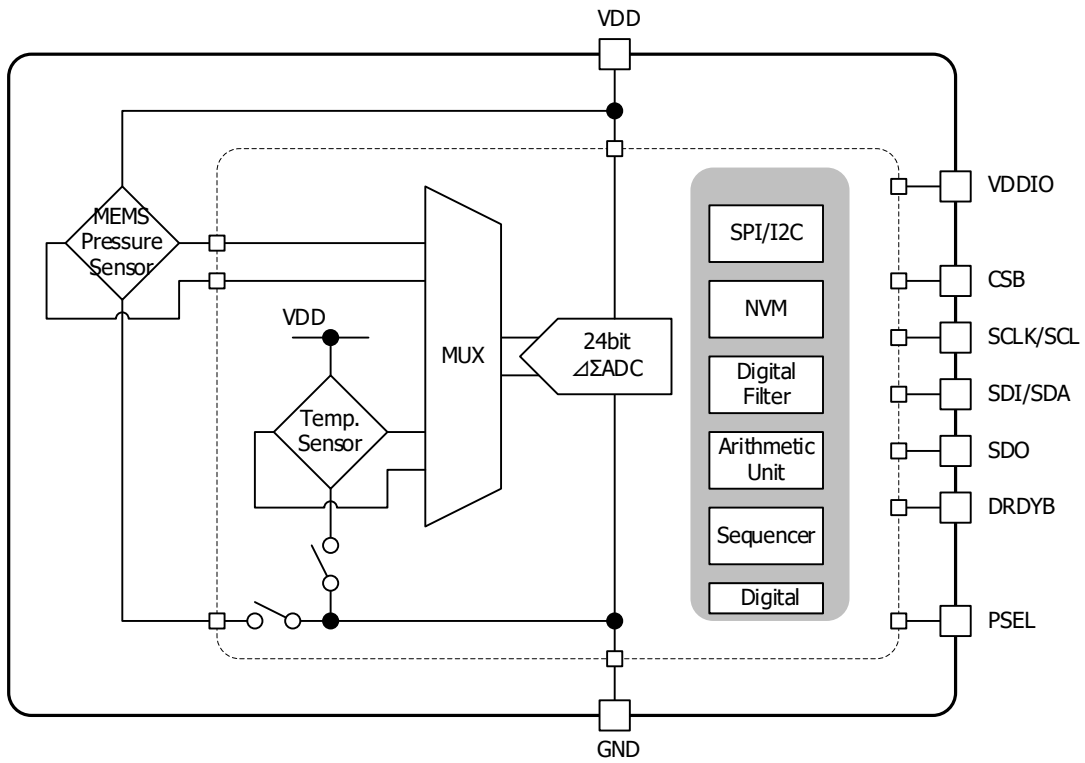


Fig.1 Block diagram

PIN CONFIGURATION

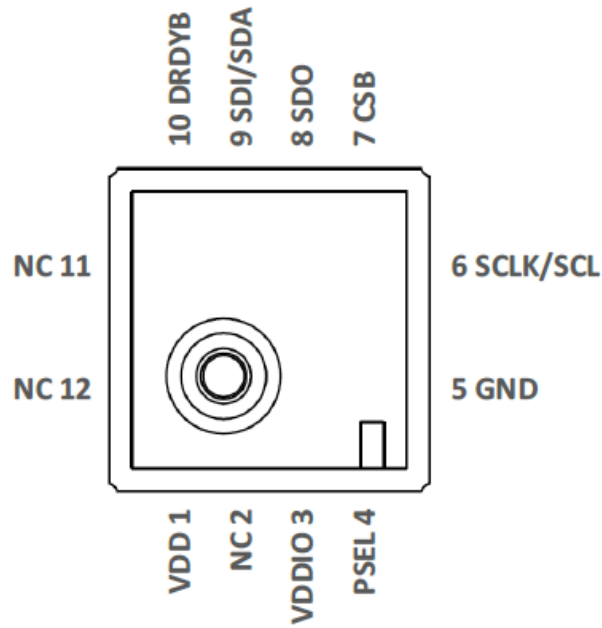


Fig. 2 Pin configuration (Top view)

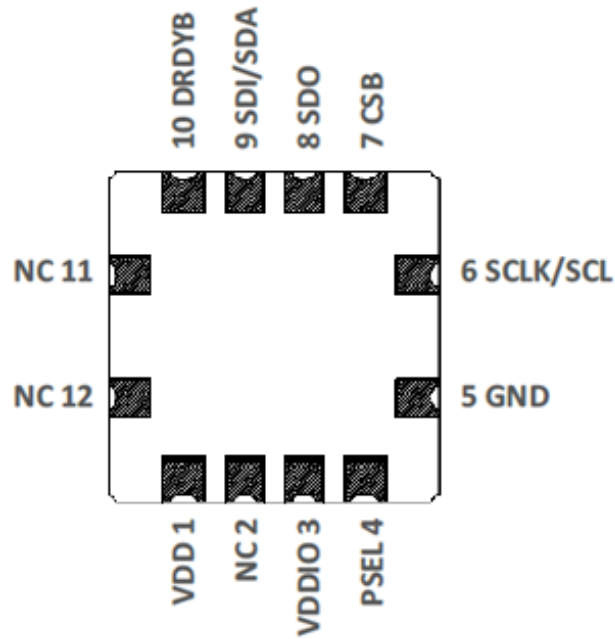


Fig. 3 Pin configuration (Bottom view)

## TERMINAL EXPLANATIONS

Table 1 Pin table

No.	Pin Name	Type	Function
1	VDD	I	Power-supply for analog circuit
2	NC	-	No connect.
3	VDDIO	I	Power-supply for digital I/O
4	PSEL	I	Protocol select terminal(High : SPI/Low:I2C) * PSEL is not pull-up / pull-down in the internal circuit. Please use it must be connected to VDDIO or GND.
5	GND	-	GND
6	SCLK SCL	I I/O	Serial clock for SPI communication (SCLK) Serial clock for I2C communication (SCL)
7	CSB	I	Chip select for SPI communication *Please set to open circuit when I2C is used
8	SDO	O	Serial Data Output for SPI communication (SDO=MISO) *Please set to open circuit when I2C is used
9	SDI SDA	I I/O	Serial Data Input for SPI communication (SDI=MOSI) Serial Data (Input and output) for I2C communication (SDA)
10	DRDYB	O	Output terminal which notifies the completion of pressure measurement and calculation correction (negative logic)
11	NC	-	No connect.
12	NC	-	No connect.

## ABSOLUTE MAXIMUM RATINGS

(unless otherwise specified, Ta=25°C)

Item	Symbol	Min.	Max.	Unit
Storage temperature range	T <sub>STG</sub>	-40	85	°C
Analog supply voltage	VDD <sub>MAX</sub>	-0.3	4.0	V
Digital I/O voltage	VDDIO <sub>MAX</sub>	-0.3	4.0	V
Overpressure (note <sup>1</sup> )	P <sub>MAX</sub>	-80 (-7.845)	+80 (+7.845)	cmH2O (kPa)
Burst pressure (note <sup>2</sup> )	P <sub>Burst</sub>	-500 (-49)	+500 (+49)	cmH2O (kPa)
Pressure medium (note <sup>3</sup> )	-	AIR ( don't dewfall )		-

note<sup>1</sup>: Overpressure is the maximum pressure to which the device can be taken and still meet specifications when return to the Operating pressure range.

note<sup>2</sup>: Burst pressure is the pressure at which the IC is damaged and leaks occur.

note<sup>3</sup>: Storage and operation in an environment of dry and non-corrosive gases.

## RECOMMENDED OPERATING CONDITIONS

(unless otherwise specified, Ta=25°C)

Item	Symbol	Min.	Typ.	Max.	Unit
Operating temperature range	T <sub>OPR</sub>	0	-	50	°C
Analog supply voltage	VDD <sub>OPR</sub>	3.0	3.3	3.6	V
Digital input voltage	VDDIO <sub>OPR</sub>	1.2	-	3.6	V
Operating pressure range	P <sub>OPR</sub>	-40 (-3.922)	-	+40 (+3.922)	cmH2O (kPa)

## ELECTRICAL CHARACTERISTICS

Analog characteristics  
(unless Ta=25°C, VDD=VDDIO=3.3V)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit.
VDD Current consumption	I <sub>VDDact</sub>	Pressure measure active	640	800	960	μA
	I <sub>VDDsd</sub>	Shutdown	-	0.01	0.1	
VDDIO Current consumption	I <sub>VDDIOact</sub>	Pressure measure active	1.4-	2.5	3.0	μA
	I <sub>VDDIOsd</sub>	Shutdown	-	0.1	1.0	
Conversion time (note <sup>4</sup> )	t <sub>con1</sub>	MODE1	0.381	0.391	0.401	msec
	t <sub>con2</sub>	MODE2	0.762	0.782	0.802	
	t <sub>con3</sub>	MODE3	1.524	1.564	1.604	
	t <sub>con4</sub>	MODE4	3.048	3.128	3.208	

note<sup>4</sup>: The conversion time is longer when the temperature is measured once every 256 times and the characteristic correction is updated.

## Digital I/O

(unless otherwise specified,  $T_a=25^{\circ}\text{C}$ ,  $V_{DD}=3.0\sim 3.6\text{V}$ ,  $V_{DDIO}=1.2\sim 3.6\text{V}$ )

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
High level input voltage	$V_{IH}$	-	$0.8 \times V_{DDIO}$	-	$V_{DDIO} + 0.3$	V
Low level input voltage	$V_{IL}$	-	-0.3	-	$0.2 \times V_{DDIO}$	V
Output voltage High level	$V_{OH1}$	$V_{DDIO} \geq 2.0\text{V}$ $I_{OH} = -3\text{mA}$	$V_{DDIO} - 0.4$	-	-	V
	$V_{OH2}$	$V_{DDIO} < 2.0\text{V}$ $I_{OH} = -1\text{mA}$	$0.8 \times V_{DDIO}$	-	-	V
Output voltage Low level	$V_{OL1}$	$V_{DDIO} \geq 2.0\text{V}$ $I_{OL} = 3\text{mA}$	-	-	0.4	V
	$V_{OL2}$	$V_{DDIO} < 2.0\text{V}$ $I_{OL} = 1\text{mA}$	-	-	$0.2 \times V_{DDIO}$	V



## Pressure sensor characteristics

(unless otherwise specified,  $T_a=25^{\circ}\text{C}$ ,  $V_{DD}=3.3\text{V}$ ,  $V_{DDIO}=1.2\sim 3.6\text{V}$ )

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Pressure resolution	$P_{\text{Res}}$	-	-	0.00001	-	cmH <sub>2</sub> O
Pressure effective resolution	$P_{\text{Eres1}}$	MODE1 ( $t_{\text{con1}} = \text{Typ } 0.4\text{ms}$ )	-	0.019	0.076	cmH <sub>2</sub> O RMS
	$P_{\text{Eres2}}$	MODE2 ( $t_{\text{con2}} = \text{Typ } 0.8\text{ms}$ )	-	0.009	0.036	
	$P_{\text{Eres3}}$	MODE3 ( $t_{\text{con3}} = \text{Typ } 1.6\text{ms}$ )	-	0.004	0.016	
	$P_{\text{Eres4}}$	MODE4 ( $t_{\text{con4}} = \text{Typ } 3.2\text{ms}$ )	-	0.002	0.008	
Pressure linearity	$H_{\text{hys}}$	-40 ~ +40cmH <sub>2</sub> O $T_a = 0^{\circ}\text{C} \sim 50^{\circ}\text{C}$	-0.11	-	0.11	%FS
Pressure measurement error	$t_{\text{HRESP}}$	-40 ~ +40cmH <sub>2</sub> O $T_a = 0^{\circ}\text{C} \sim 50^{\circ}\text{C}$	-0.5	-	0.5	%FS

## Temperature sensor characteristics

(unless otherwise specified,  $T_a=25^{\circ}\text{C}$ ,  $V_{DD}=3.3\text{V}$ ,  $V_{DDIO}=1.2\sim 3.6\text{V}$ )

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Temperature measurement error	$T_{\text{acc}}$	$0^{\circ}\text{C} \sim 50^{\circ}\text{C}$	-2.0	-	2.0	$^{\circ}\text{C}$

## Definition of characteristics

Pressure measurement value  $P_{\text{result}}$

It is the device output value obtained by Read Pressure Result Command.

Pressure resolution  $P_{\text{Res}}$

This Value is equivalent to 1LSB of output digital value.

Pressure effective resolution  $P_{\text{Eres}}$

Measure 16 points after the pressure output is stable, and it is the standard deviation of the 16 points.

Pressure linearity  $P_L$

It is the amount of deviation from the Ref. line connecting measurement value  $-40\text{cmH}_2\text{O}$  with  $+40\text{cmH}_2\text{O}$ .

Pressure measurement error  $P_{\text{Err}}$

It is the deviation amount of the Pressure measurement value from the ideal line.

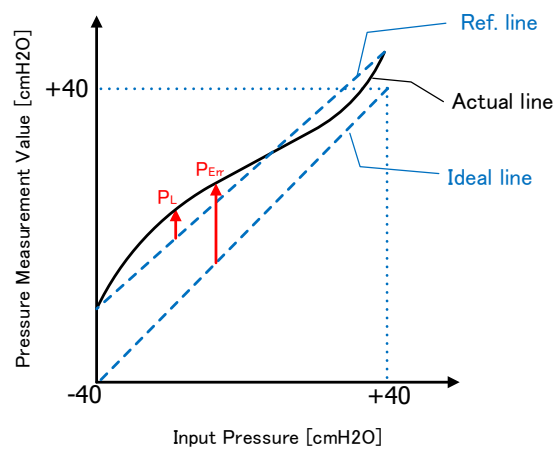


Fig. 4 Definition of Characteristics

## FUNCTION EXPLANATION

### Function Outline

The MMR920C04 is consists of piezo resistive pressure sensor and an analog front end IC.

It converts analog output voltage from piezo resistive pressure sensor to digital value of 24 bits, and corrects and outputs variations of sensor characteristics due to variations of temperature and process.

Conversion time and Pressure effective resolution are selectable with the mode of different four. Conversion time and Pressure effective resolution are in the relationship of trade-off.

Noise reduction is possible by a built-in Low Pass Filter. Cutoff frequency of Low Pass Filter can be changed.

State transition table

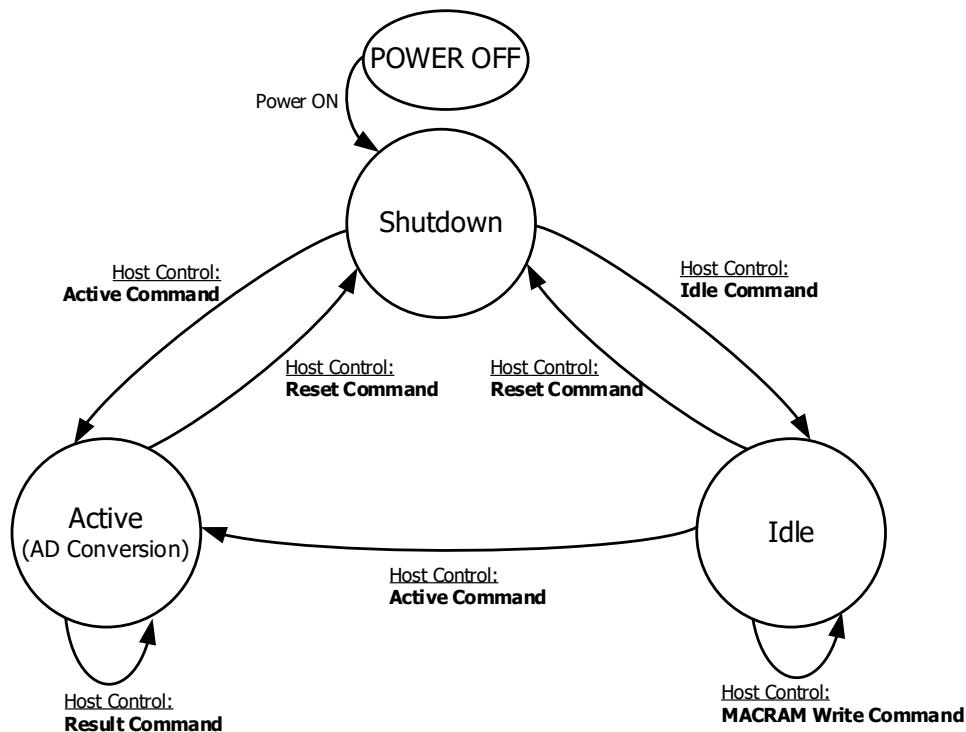


Fig. 5 State transition diagram

Table 2 State transition table

State Command	Shutdown	Active	Idle
Reset	Power on Reset & Initial Boot =>Shutdown	Power on Reset & Initial Boot =>Shutdown	Power on Reset & Initial Boot =>Shutdown
Active	Reset & Boot Load =>Active state(AD conversion)	Ignore(note <sup>5</sup> ) =>Keep state	=>Active state (AD conversion)
Result	Ignore(note <sup>5</sup> ) =>Keep state	Output result =>Keep state	Do not issue(note <sup>6</sup> ) =>Keep state
Idle	Reset & Boot Load =>Idle state	Do not issue(note <sup>7</sup> ) =>Idle state	=>Keep state
MACRAM Write	Ignore(note <sup>5</sup> ) =>Keep state	Do not issue(note <sup>7</sup> ) =>Keep state	Change cutoff frequency =>Keep state
Status	Output code =>Keep state	Output code =>Keep state	Output code =>Keep state

note<sup>5</sup>: NACK is returned to the command.

note<sup>6</sup>: The correct result isn't output. Additionally, ACK is returned to the command.

note<sup>7</sup>: Although command is acceptable, it goes unintended behavior since sequence is running.

Command code

Table 3 Command code list

Command Name		Command Code									Applicable format
		HEX.	BIN.								
			C7	C6	C5	C4	C3	C2	C1	C0	
Reset		0x72	0	1	1	1	0	0	1	0	<a href="#">SPI Write format</a> <a href="#">I2C Write format</a>
	Reset and Return to Shutdown state. It becomes busy for the maximum 1.8msec.										
Idle		0x94	1	0	0	1	0	1	0	0	<a href="#">SPI Write format</a> <a href="#">I2C Write format</a>
	Start up the internal circuit and put it in the idle state.										
Active	Measure at MODE 1	0xA0	1	0	1	0	0	0	0	0	<a href="#">SPI Write format</a> <a href="#">I2C Write format</a>
	Measure at MODE 2	0xA2	1	0	1	0	0	0	1	0	
	Measure at MODE 3	0xA4	1	0	1	0	0	1	0	0	
	Measure at MODE 4	0xA6	1	0	1	0	0	1	1	0	
Start AD conversion.											
Read Pressure Result	Normal	0xC0	1	1	0	0	0	0	0	0	<a href="#">SPI Write/Read format</a> <a href="#">I2C Combined format</a>
	With Low Pass Filter	0xC4	1	1	0	0	0	1	0	0	
		Read compensated pressure result. It outputs the result of pressure measurement at 24bits, MSB first. A negative number is expressed by 2's complement. About output range, in case of positive output : 000000 h ~ 7FFFFFF h (in decimal number : 0 ~ +8388607), in case of negative output : FFFFFFF h ~ 800000 h (in decimal number : -1 ~ -8388608) However, the result of measurement when being used beyond a recommended operating condition can't be guaranteed.  Pressure value = DEC. / 10 <sup>5</sup> Output example:									
		BIN.				HEX.		DEC.		Pressure	
		111110000101111011100000 b				F85EE0 h		-500000		-5.00000cmH2O	
		000000000000000000000000 b				000000 h		0		0.00000cmH2O	
		001111010000100100000000 b				3D0900 h		4000000		40.00000cmH2O	

Table 4 Command code list (continued)

Command Name	Command Code									Applicable format																																			
	HEX.	BIN.																																											
		C7	C6	C5	C4	C3	C2	C1	C0																																				
Read Temperature Result	0xC2	1	1	0	0	0	0	1	0	<a href="#">SPI Write/Read format</a> <a href="#">I2C Combined format</a>																																			
	<p>Read compensated temperature result.                      It outputs the result of pressure measurement at 24bits, MSB first.                      A negative number is expressed by 2's complement.                      About output range, in case of positive output : 000000 h ~ 7FFFFFFF h (in decimal number : 0 ~ +8388607), in case of negative output : FFFFFFFF h ~ 800000 h (in decimal number : -1 ~ -8388608)                      However, the result of measurement when being used beyond a recommended operating condition can't be guaranteed.</p> <p>Temperature value = DEC. / 2<sup>7</sup></p> <p>Output example:</p> <table border="1"> <thead> <tr> <th>BIN.</th> <th>HEX.</th> <th>DEC.</th> <th>Temperature</th> </tr> </thead> <tbody> <tr> <td>00000000000000000000000000000000 b</td> <td>000000 h</td> <td>0</td> <td>0.000 °C</td> </tr> <tr> <td>00000000000011001000000000 b</td> <td>000C80 h</td> <td>3200</td> <td>25.000 °C</td> </tr> <tr> <td>00000000000110010000000000 b</td> <td>001900 h</td> <td>6400</td> <td>50.000 °C</td> </tr> </tbody> </table>										BIN.	HEX.	DEC.	Temperature	00000000000000000000000000000000 b	000000 h	0	0.000 °C	00000000000011001000000000 b	000C80 h	3200	25.000 °C	00000000000110010000000000 b	001900 h	6400	50.000 °C																			
BIN.	HEX.	DEC.	Temperature																																										
00000000000000000000000000000000 b	000000 h	0	0.000 °C																																										
00000000000011001000000000 b	000C80 h	3200	25.000 °C																																										
00000000000110010000000000 b	001900 h	6400	50.000 °C																																										
Status	0x80	1	0	0	0	0	0	0	0	<a href="#">SPI Write/Read format</a> <a href="#">I2C Combined format</a>																																			
	<p>Output 8bits data depending on the IC conditions</p> <table border="1"> <thead> <tr> <th>D7</th> <th>D6</th> <th>D5</th> <th>D4</th> <th>D3</th> <th>D2</th> <th>D1</th> <th>D0</th> <th>State</th> </tr> </thead> <tbody> <tr> <td>0</td> <td>0</td> <td>0</td> <td>0</td> <td>0</td> <td>0</td> <td>0</td> <td>0</td> <td>Shutdown</td> </tr> <tr> <td>1</td> <td>1</td> <td>1</td> <td>0</td> <td>0</td> <td>1</td> <td>0</td> <td>1</td> <td>Idle</td> </tr> <tr> <td>1</td> <td>1</td> <td>1</td> <td>0</td> <td>1</td> <td>1</td> <td>0</td> <td>1</td> <td>Active</td> </tr> </tbody> </table>										D7	D6	D5	D4	D3	D2	D1	D0	State	0	0	0	0	0	0	0	0	Shutdown	1	1	1	0	0	1	0	1	Idle	1	1	1	0	1	1	0	1
D7	D6	D5	D4	D3	D2	D1	D0	State																																					
0	0	0	0	0	0	0	0	Shutdown																																					
1	1	1	0	0	1	0	1	Idle																																					
1	1	1	0	1	1	0	1	Active																																					
MACRAM Write	0xE4	1	1	1	0	0	1	0	0	<a href="#">SPI MACRAM Write format</a> <a href="#">I2C MACRAM Write format</a> (special format)																																			
	<p>It is used for writing filter coefficient. For the filter coefficient, refer to <a href="#">10-6. LowPassFilter</a>.</p>																																												



Timing Chart

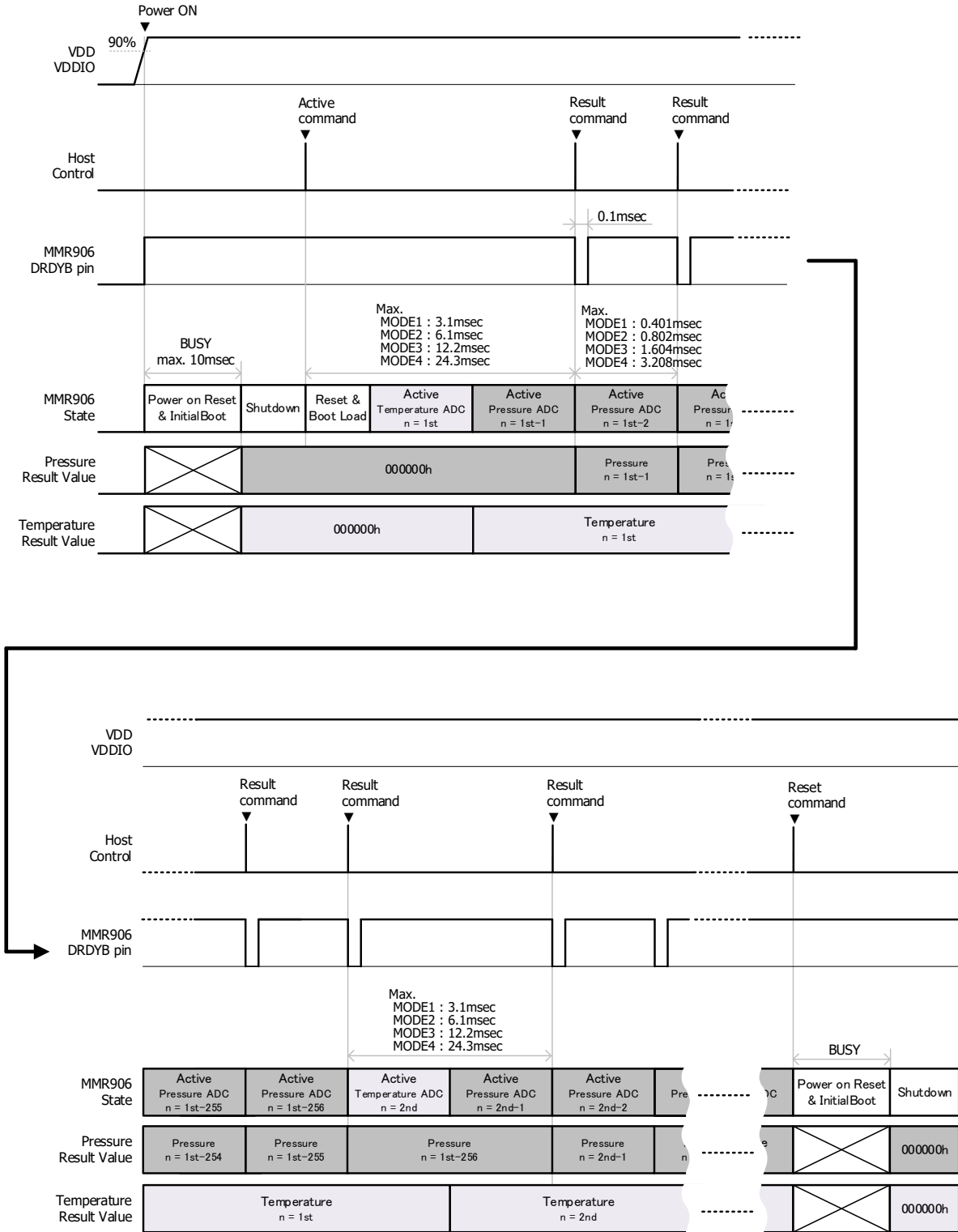


Fig. 7 Timing Chart



Low Pass Filter

Noise reduction is possible by a built-in Low Pass Filter. Pressure value with Low Pass Filter applied can be got using command code 0xC4. Cutoff frequency  $f_c$  can be changed by filter coefficient 4Bytes calculated by the equation (1). Filter coefficient is written to the IC using the MACRAM Write command in the idle state. Filter coefficient is cleared to the default value in the shutdown state.

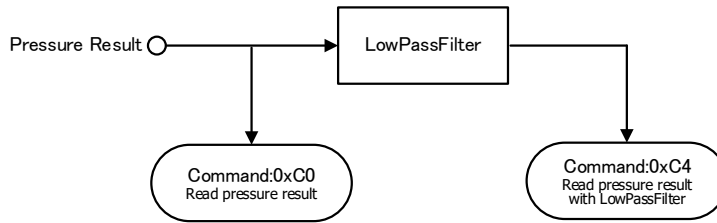


Fig. 8 Low Pass Filter Configuration

Table 5 example of character with Low Pass Filter

Cutoff frequency		No filter	fc=10Hz	fc=100Hz
Pressure effective resolution example [cmH2O RMS]	MODE1	0.019	0.012	0.0068
	MODE2	0.008	0.0064	0.0034
	MODE3	0.0044	0.0036	0.0022
	MODE4	0.0025	0.0023	0.0013

Filter coefficient equation

$$\text{Filter coefficient(4Bytes)} = 2^{27} \times \exp(-2\pi \times f_c \times t_{con}) \dots \dots \dots (\text{Eq1})$$

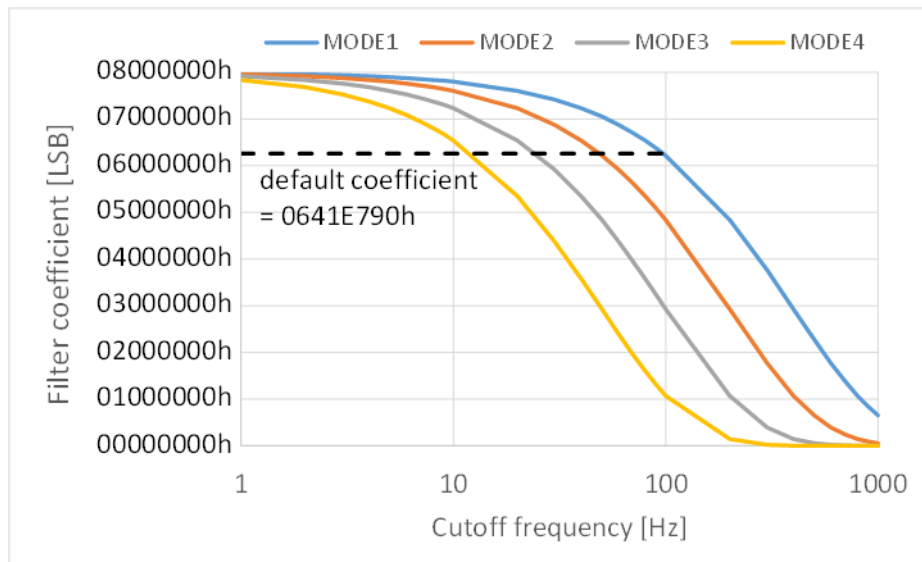


Fig. 9 Filter coefficient example

## SERIAL INTERFACE

It supports SPI and I2C as an interface for serial communication. SPI (max. 5Mbps) or I2C (max.3.4Mbps) can be selected by PSEL terminal. When PSEL terminal is set to High, SPI will be selected. When it is set to Low, I2C will be selected. Please set High voltage of PSEL terminal the same potential as VDDIO terminal.

## Baud rate

※ This item is not inspected at the time of shipment.  
(unless otherwise specified, Ta=25°C, VDD=3.0~3.6V)

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
I2C communication speed	BR <sub>I2C1</sub>	VDDIO ≥ 2.0V Cb ≤ 100pF	-	-	3.4	Mbps
	BR <sub>I2C2</sub>	VDDIO < 2.0V Cb < 100pF	-	-	0.4	
	BR <sub>I2C3</sub>	VDDIO ≥ 2.0V Cb ≤ 400pF	-	-	1.7	
	BR <sub>I2C4</sub>	VDDIO < 2.0V Cb < 400pF	-	-	0.4	
SPI communication speed	BR <sub>SPI1</sub>	VDDIO ≥ 2.0V Cb ≤ 100pF	-	-	5.0	
	BR <sub>SPI2</sub>	VDDIO < 2.0V Cb < 100pF	-	-	1.0	
	BR <sub>SPI3</sub>	VDDIO ≥ 2.0V Cb ≤ 400pF	-	-	2.5	
	BR <sub>SPI4</sub>	VDDIO < 2.0V Cb < 400pF	-	-	0.5	

SPI AC Characteristics

※ This item is not inspected at the time of shipment.

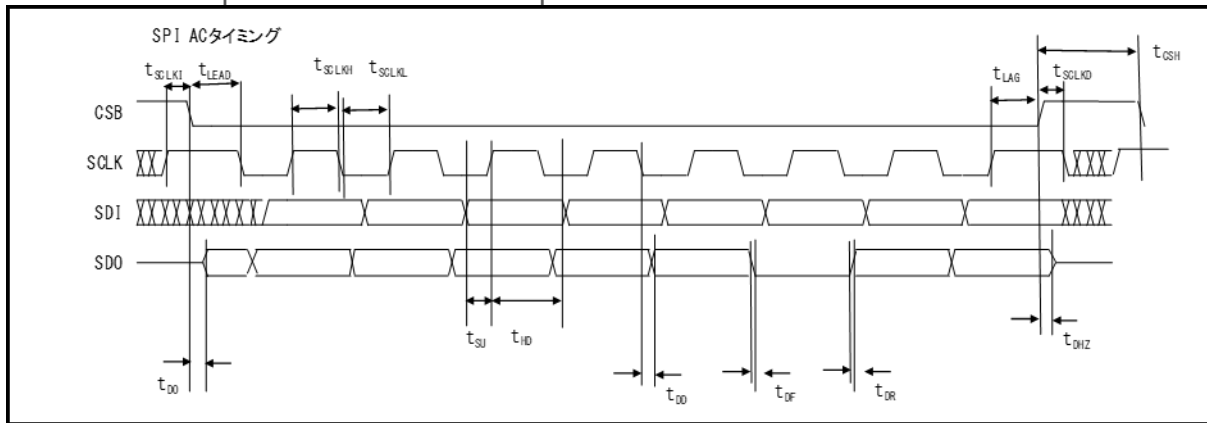


Fig. 10 SPI AC timing chart

Table 6 SPI AC Characteristics

Items	Symbol	VDDIO<2V		VDDIO≥2V		Unit
		min.	max.	min.	max.	
SCLK frequency (Duty 50±10%)	$f_{SCLK}$	-	1	-	5	MHz
SCLK High period (90%~90%)	$t_{SCLKH}$	400		80	-	ns
SCLK Low period (10%~10%)	$t_{SCLKL}$	400		80	-	ns
SCLK wait time	$t_{SCLKI}$	500	-	100	-	ns
SCLK Delay time	$t_{SCLKD}$	0	-	0	-	ns
CSB High period (90%~90%)	$t_{CSH}$	1000	-	200	-	ns
Time from CSB falling to SCLK falling	$t_{LEAD}$	0	-	0	-	ns
Time from SCLK rising to CSB rising	$t_{LAG}$	500	-	100	-	ns
SDI setup time	$t_{SU}$	100	-	10	-	ns
SDI hold time	$t_{HD}$	10	-	10	-	ns
SDO rise time(Load100pF) (10%~90%)	$t_{DR}$		50	-	50	ns
SDO fall time(Load100pF) (10%~90%)	$t_{DF}$		50	-	50	ns
SDO output delay time(Load100pF)	$t_{DDY}$	-	120	-	60	ns
Time from CSB falling to SDO output(Load 100pF)	$t_{ACC}$	-	120	-	60	ns
Time from CSB rising to SDO output HiZ(Load 100pF)	$t_{DHZ}$	-	170	-	170	ns

SPI format

The basic format of SPI is shown below. The relationship between clock (SCLK) and data (SDI/SDO) is Mode3. Data send/receive is started when CSB becomes low level from the status when SCLK is high level. Data is updated on falling edges of the SCLK, and sampled on rising edges of the SCLK. Data send/receive is ended when CSB becomes high level from the status when SCLK is high level.

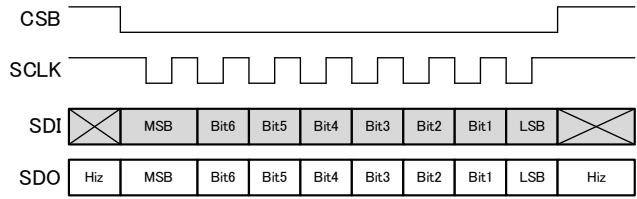


Fig. 11 SPI Waveform

SPI Write form

Please send command code of 8 bits. When their commands are received, it turns over ACK to 8 bits.



Fig. 12 SPI Write forma

SPI Write/Read format

Please send command code of 8 bits. When the command is received, it turns over ACK to 8 bits and it outputs the data MSB first.

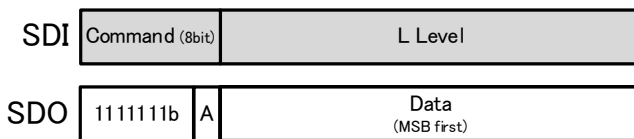


Fig. 13 SPI Write/Read format

SPI MACRAM Write format

Please send command code (0xE4) and memory address (0x6F). When command is received, it turns over ACK to 8 bits. Then please send Filter coefficient of 4Bytes MSB first. After receiving data, it becomes busy for the maximum 15msec in order to data- writing. During this time, 00h which indicates busy is output. When data- writing is completed, 01h is output.

How to discern busy:

After sending write data, continue to input clock with maintaining communicating mode. Then, 00h is output to indicate that it is busy. When the writing has been completed, 01h will be output. \*The "00h" to indicate busy may sometimes be output or not depending on the clock frequency.

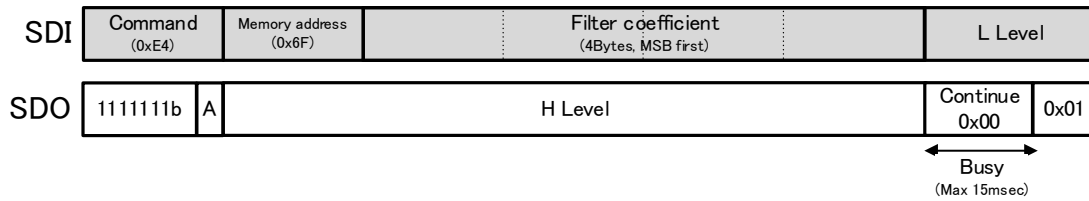


Fig. 14 SPI MACRAM Write forma

SPI ACK

When command code which is send in each SPI format is received, it outputs L level to 8 bits as ACK. If command code is not accepted or command code is not valid, it outputs H Level to 8 bits as NACK.

I2C AC Characteristics

※This item is not inspected at the time of shipment

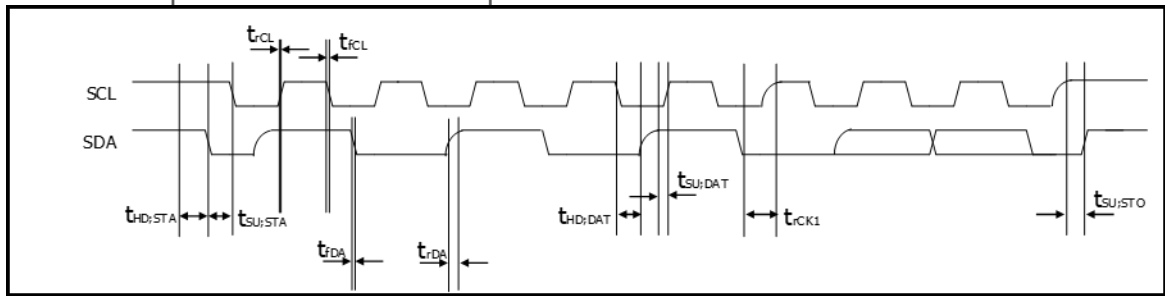


Fig.15 I2C AC timing char

Table 7 I2C AC Characteristics

Items	Symbol	VDDIO < 2.0V		VDDIO ≥ 2.0V				Unit
		Fast mode		Hsmode				
				Cb=100pF		Cb=400pF		
		min.	max.	min.	max.	min.	max.	
SCL frequency	$f_{SCL}$	0	400kHz	0	3.4	0	1.7	MHz
Start condition setup time	$t_{SU;STA}$	600	-	160	-	160	-	ns
Start condition hold time	$t_{HD;STA}$	600	-	160	-	160	-	ns
Stop condition setup time	$t_{SU;STO}$	600	-	160	-	160	-	ns
Data setup time	$t_{SU;DAT}$	100	-	20	-	20	-	ns
Data hold time (note <sup>9</sup> )	$t_{HD;DAT}$	20	-	20	70	20	150	ns
SCL rise time	$t_{rCL}$	-	300	10	40	20	80	ns
Rise time of SCL after ACK (When clock stretch is released.)	$t_{rCL1}$	-	300	10	80	20	160	ns
SCL fall time	$t_{fCL}$	10	300	10	-	20	80	ns
SDA rise time	$t_{rDA}$	-	300	10	80	20	160	ns
SDA fall time	$t_{fDA}$	10	300	10	80	20	160	ns

note<sup>9</sup>: This product does not have the function to retain data in SDA.  
Please ensure the hold of SDA with 20nsec for the area where SCL falling edge is not defined.

I2C format

It conforms to I2C protocol except some special formats. I2C address is the total of 8 bits. The first 7 bits are slave address and the rest of 1 bit is R/W bit. Slave address for MMR920C04 (7 bits) is 0x67. I2C address (8 bits) will be 0xCE (Write) and 0xCF (Read) by combining with R/W bit.

Table 8 I2C address

HEX.	I2C Address (8 bit)							R/W bit
	Slave address (7 bit)							
	A6	A5	A4	A3	A2	A1	A0	
0xCE	1	1	0	0	1	1	1	0
0xCF	1	1	0	0	1	1	1	1

I2C Write format

Please send I2C address of 8 bits (0xCE) by Write Mode. Then please send command code.

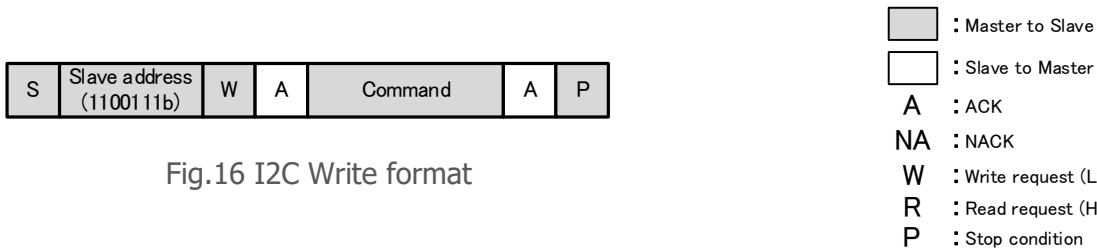


Fig.16 I2C Write format

I2C Combined format

Please send I2C address (0xCE) and the command code by Write Mode. Then please send I2C address (0xCF) by Read Mode. It outputs the data MSB first

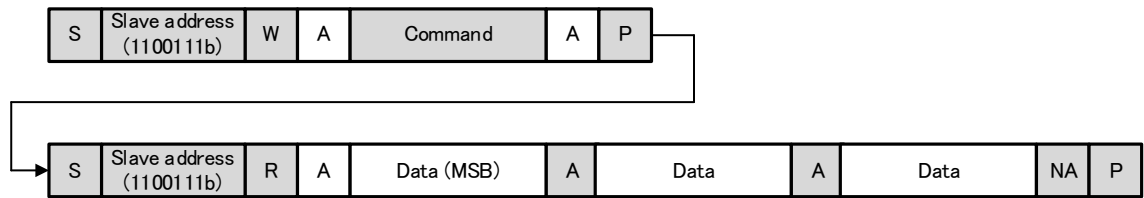


Fig. 17 I2C I2C Combined format

I2C MAC Write format (special format)

It is a format unique to this product that does not partially conform to I2C protocol. Please send I2C address (0xCE), the command (0xE4), and memory address (0x6F) by Write Mode. Then send the data of 4Bytes Filter coefficient. At this time, please be careful that NACK is returned after transmitting LSB. After receiving data, it becomes busy for the maximum 15msec in order to data- writing. During this time, SCL is put in clock stretch. When data- writing is completed, SCL is released.

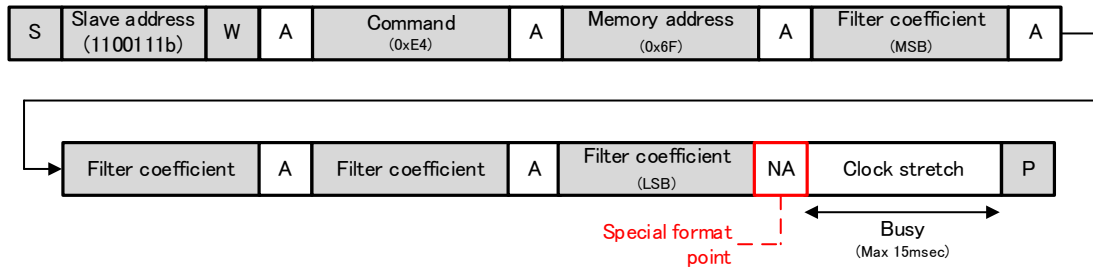


Fig. 18 I2C MACRAM Write forma



TYPICAL APPLICATION CIRCUIT

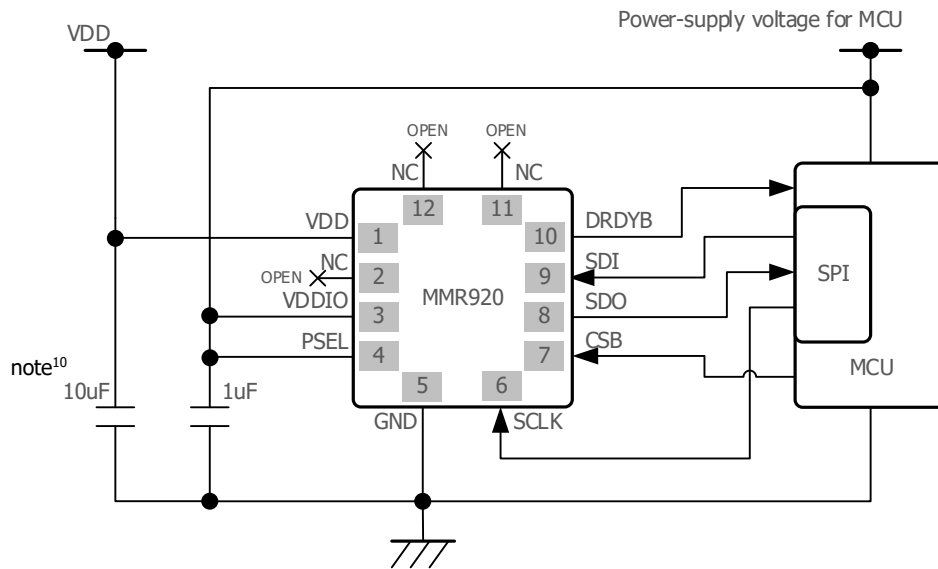


Fig. 19 Typical Electrical Connection (SPI)

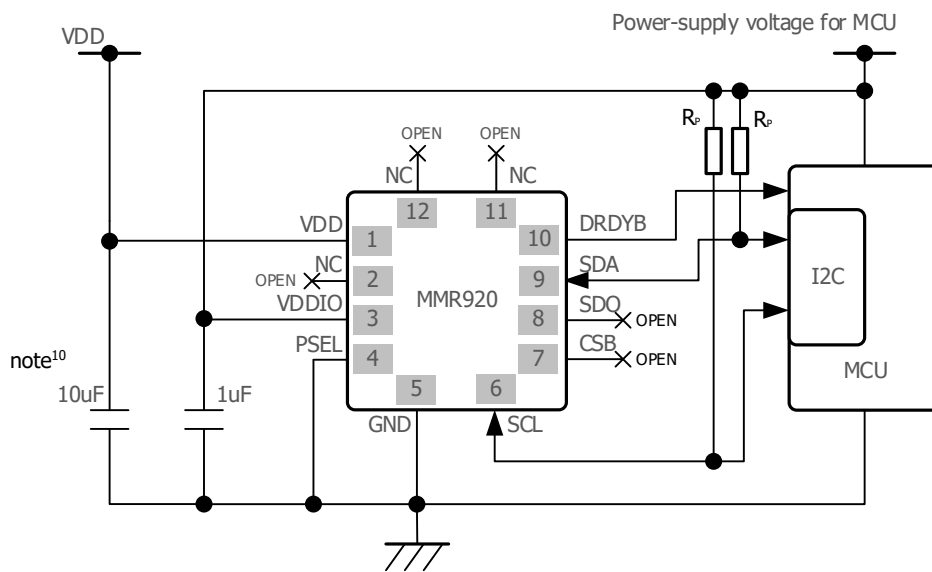


Fig. 20 Typical Electrical Connection (I2C)

note<sup>10</sup>: Place the bypass capacitor for the power supply as close to the IC as possible.

TYPICAL PERFORMANCE CHARACTERISTICS

(unless otherwise specified,  $T_a=25^{\circ}\text{C}$ ,  $V_{DD}=V_{DDIO}=3.3\text{V}$ )

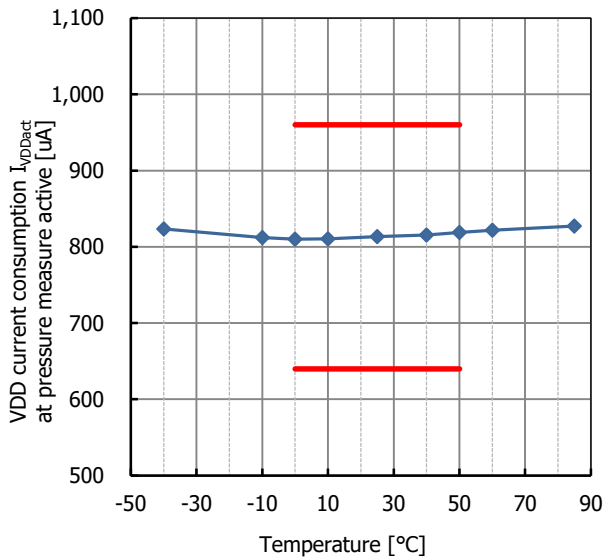


Fig.21.1 VDD current consumption  $I_{VDDact}$  at pressure measure active temperature characteristic

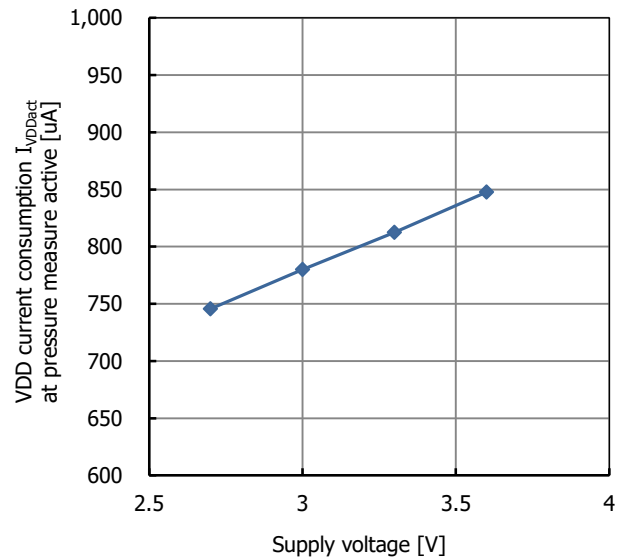


Fig.21.2 VDD current consumption  $I_{VDDact}$  at pressure measure active supply voltage characteristic

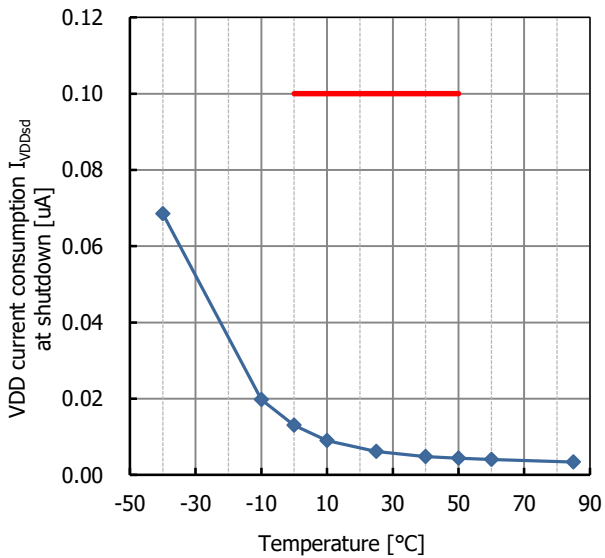


Fig.21.3 VDD current consumption  $I_{VDDsd}$  at shutdown temperature characteristic

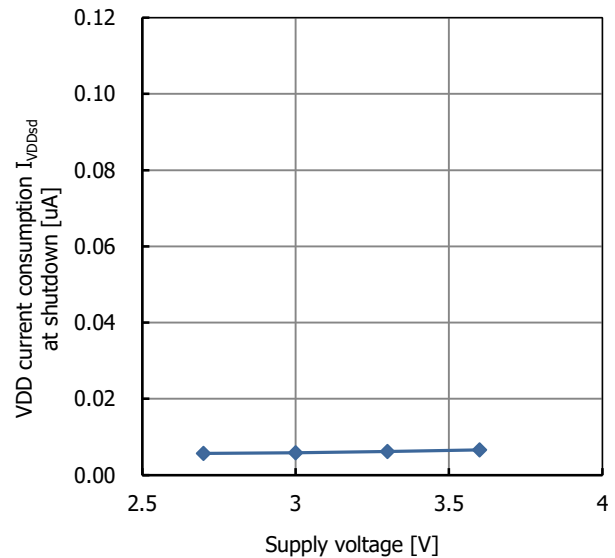


Fig.21.4 VDD current consumption  $I_{VDDsd}$  at shutdown supply voltage characteristic

(特記なき場合 / unless otherwise specified,  $T_a=25^\circ\text{C}$ ,  $V_{DD}=V_{DDIO}=3.3\text{V}$ )

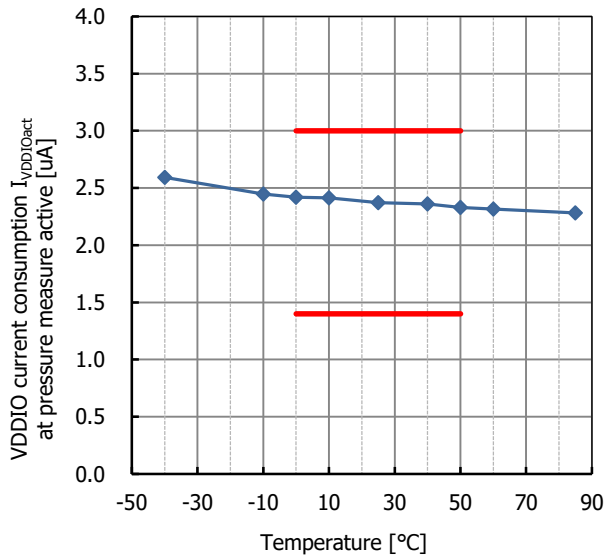


Fig.21.5 VDDIO current consumption  $I_{VDDIOact}$  at pressure measure active temperature characteristic

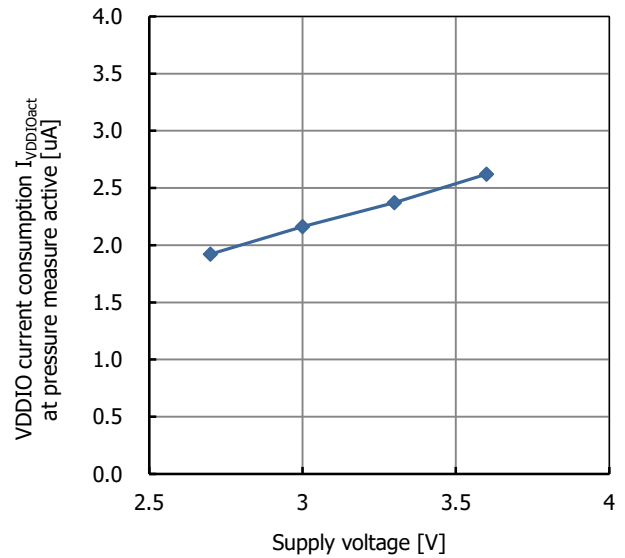


Fig.21.6 VDDIO current consumption  $I_{VDDIOact}$  at pressure measure active supply voltage characteristic

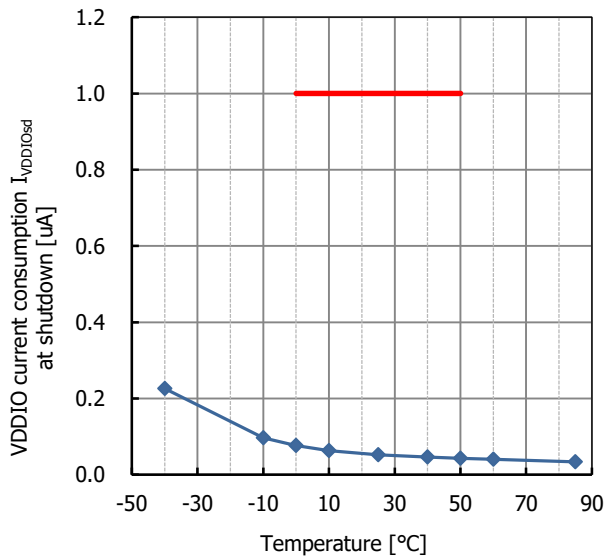


Fig.21.7 VDDIO current consumption  $I_{VDDIOsd}$  at shutdown temperature characteristic

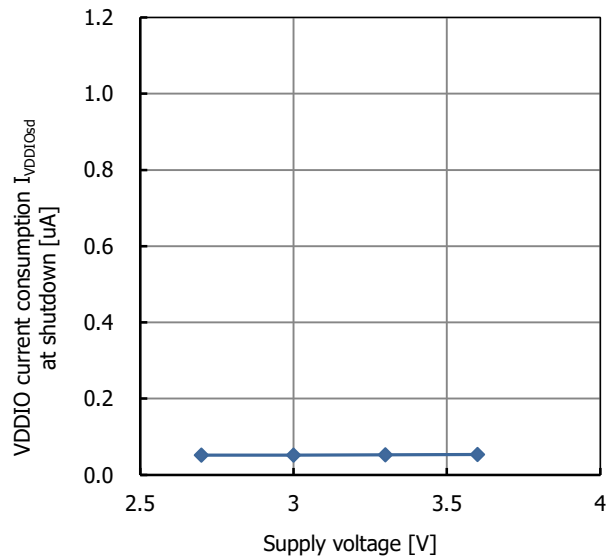


Fig.21.8 VDDIO current consumption  $I_{VDDIOsd}$  at shutdown supply voltage characteristic

(特記なき場合 / unless otherwise specified,  $T_a=25^{\circ}\text{C}$ ,  $V_{DD}=V_{DDIO}=3.3\text{V}$ )

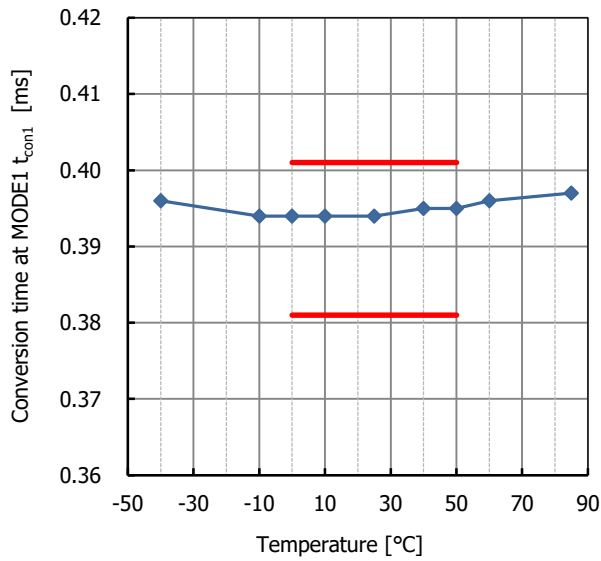


Fig.21.9 Conversion time at MODE 1 temperature characteristic

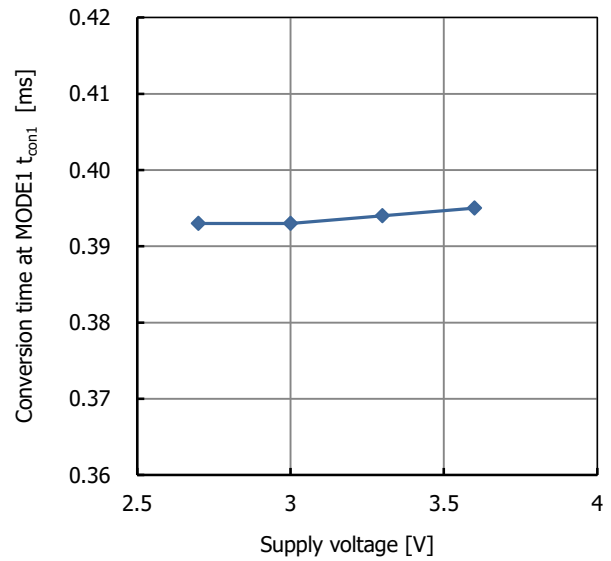


Fig.21.10 Conversion time at MODE 1 supply voltage characteristic

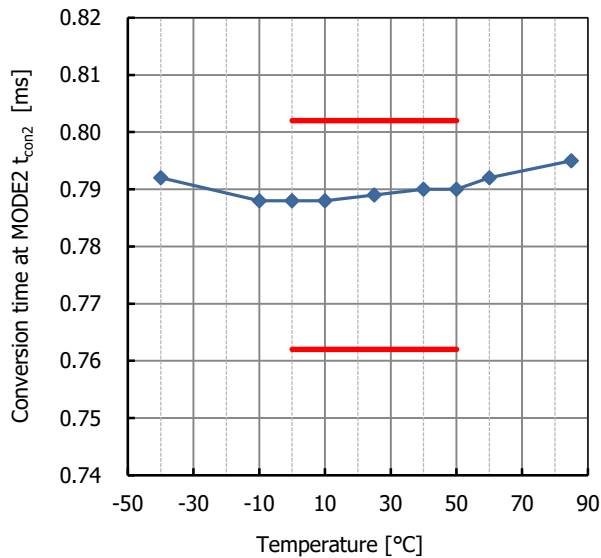


Fig.21.11 Conversion time at MODE 2 temperature characteristic

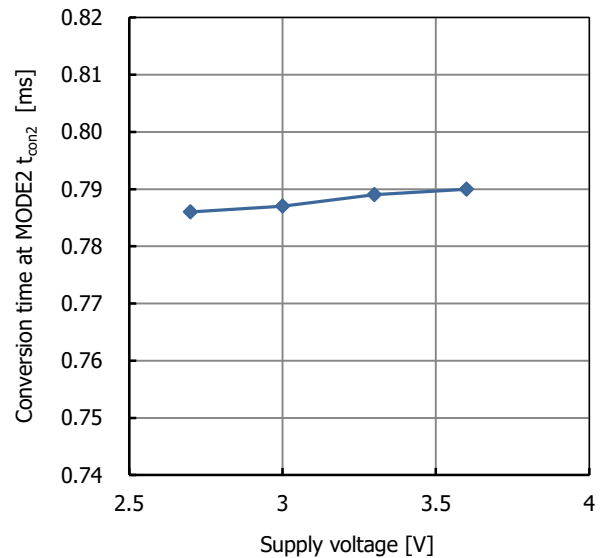


Fig.21.12 Conversion time at MODE 2 supply voltage characteristic

(特記なき場合 / unless otherwise specified, Ta=25°C, VDD=VDDIO=3.3V)

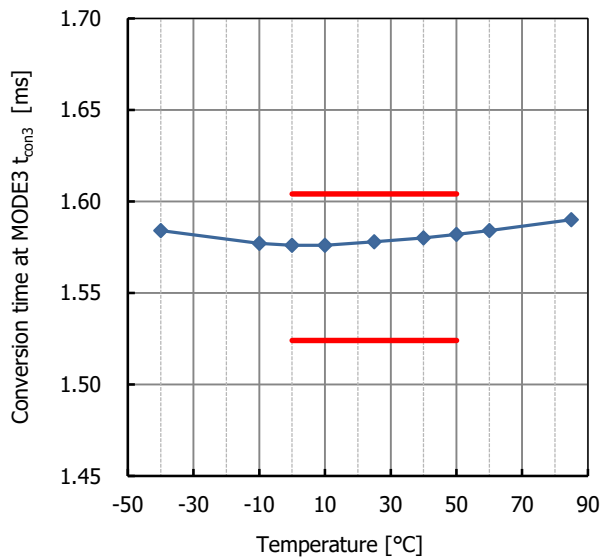


Fig.21.13 Conversion time at MODE 3 temperature characteristic

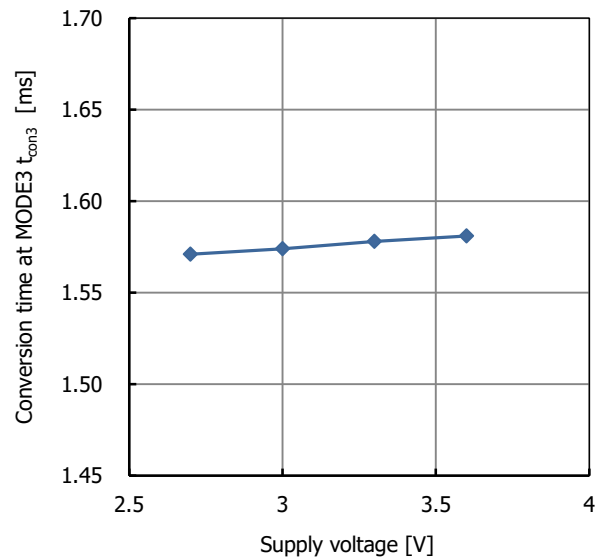


Fig.21.14 Conversion time at MODE 3 supply voltage characteristic

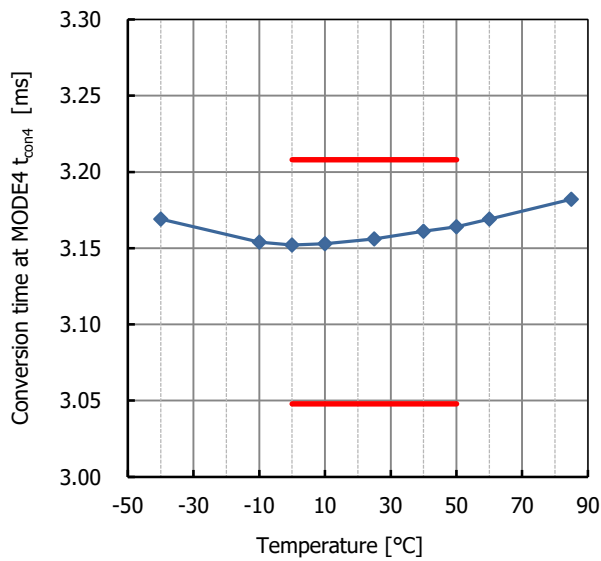


Fig.21.15 Conversion time at MODE 4 temperature characteristic

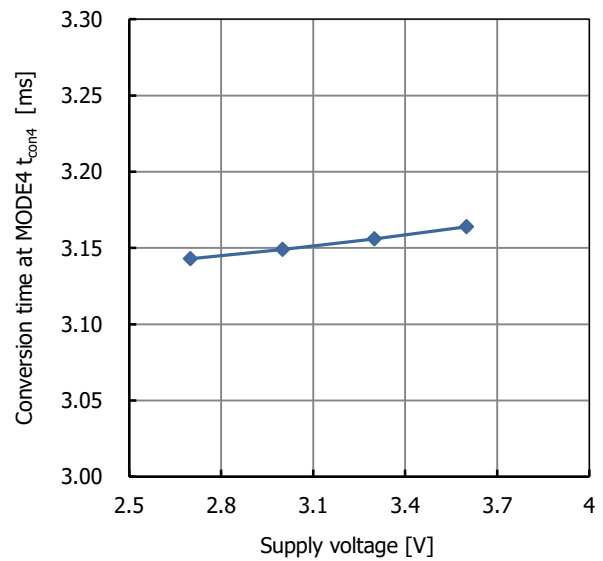


Fig.21.16 Conversion time at MODE 4 supply voltage characteristic

(特記なき場合 / unless otherwise specified, Ta=25°C, VDD=VDDIO=3.3V)

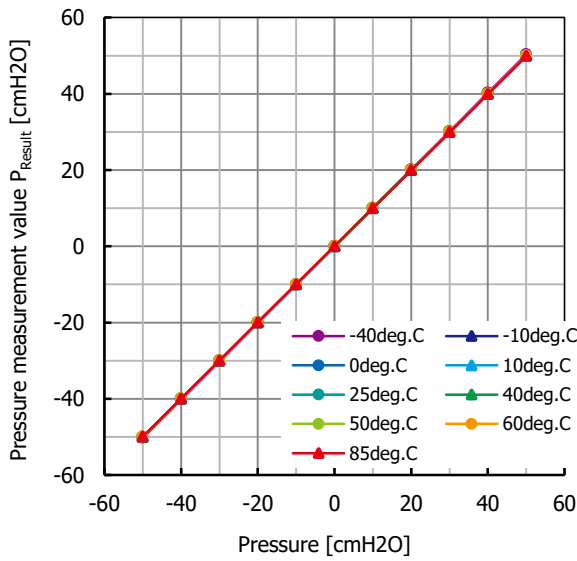


Fig.21.17 Pressure measurement value  $P_{Result}$  temperature characteristic

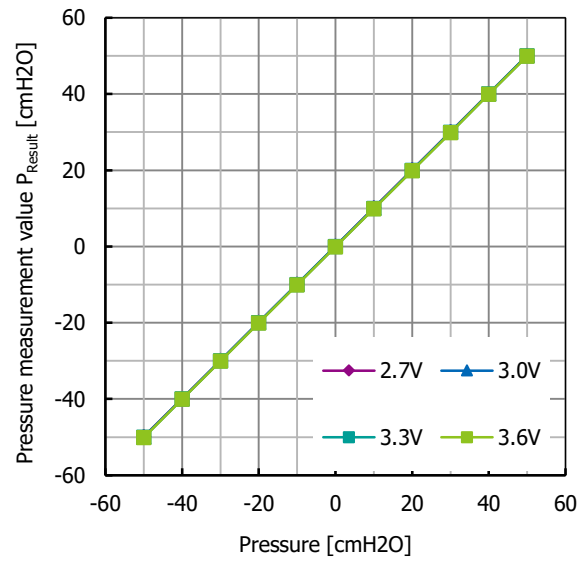


Fig.21.18 Pressure measurement value  $P_{Result}$  supply voltage characteristic

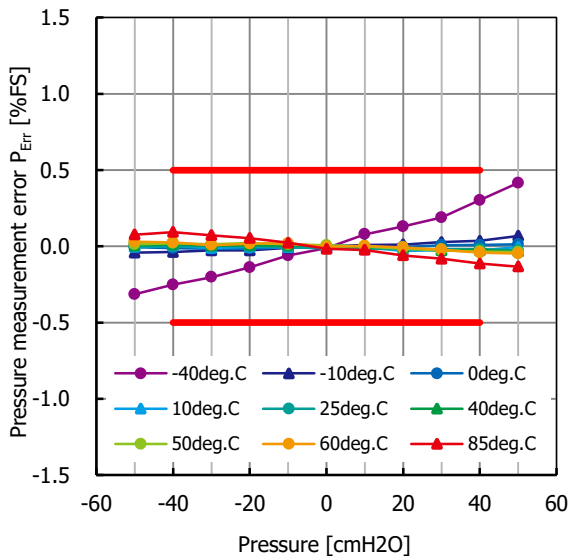


Fig.21.19 Pressure measurement error  $P_{Err}$  temperature characteristic

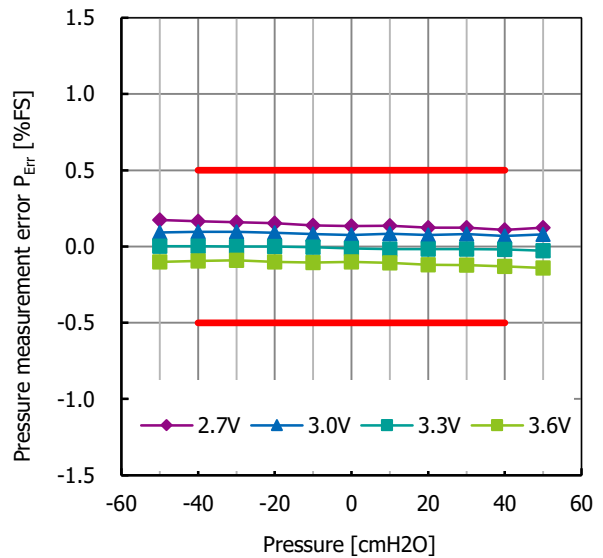
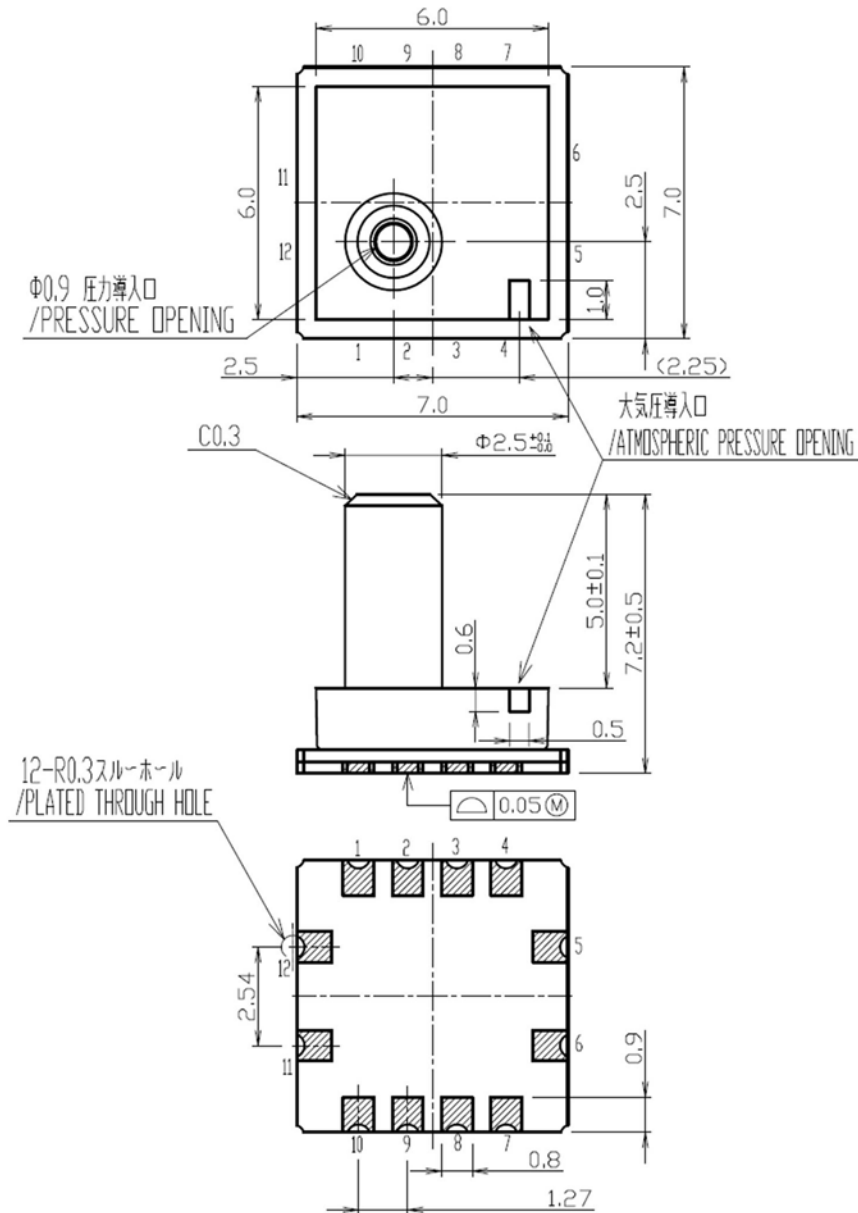


Fig.21.20 Pressure measurement error  $P_{Err}$  supply voltage characteristic

DIMENSIONS

パッケージ: MEMS-12B  
PACKAGE

UNIT	mm
------	----

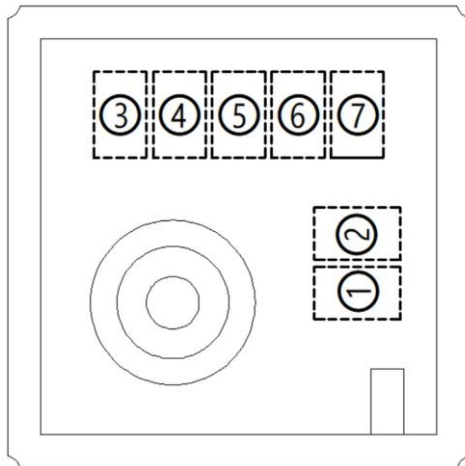


基板仕様/Print circuit board specifications

グレード Grade	-
UL UL	-
板厚 Thickness	-
構造 Structure	-
部品実装 Parts assemble	-
レジスト resist	-

No. A01-MEMS12B-0002

## MARKING CONTENTS



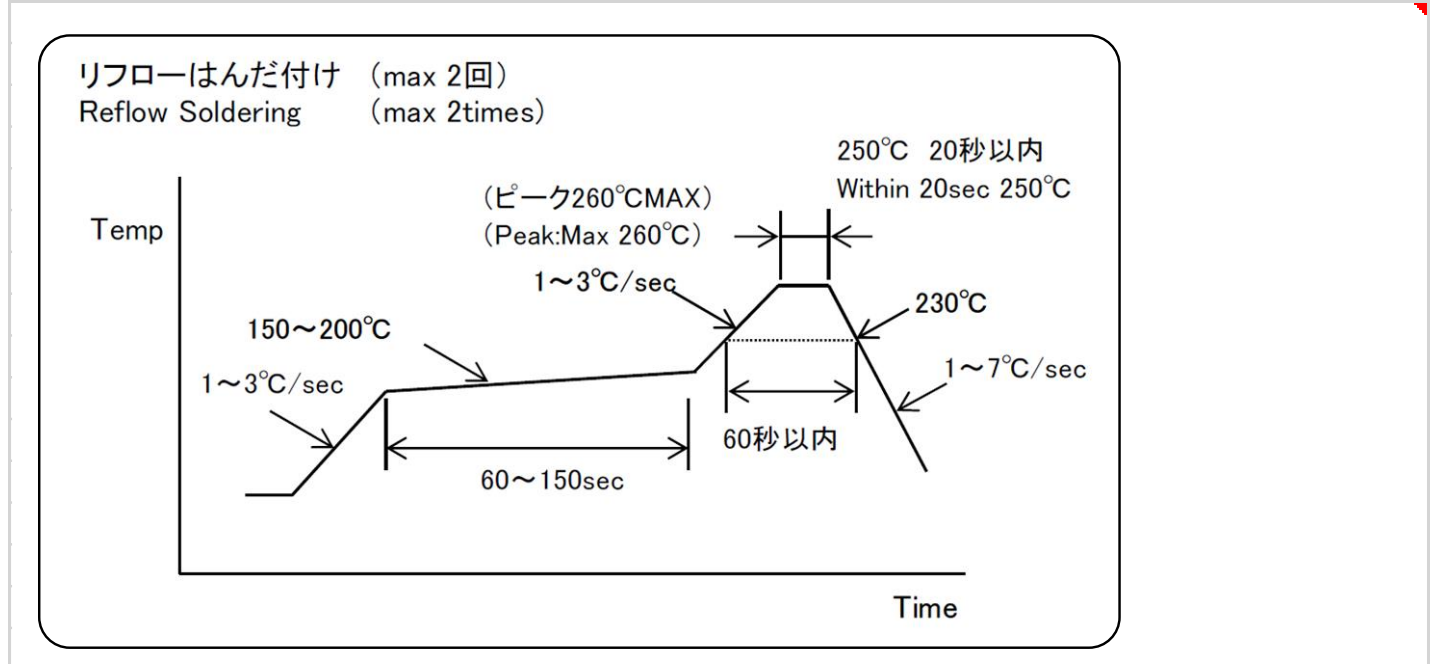
①~④	機種名/Model name		ランク/Rank	
	MMR920C04		LC04	
⑤	生産年/Production year			
⑥	生産月/Production month			
	月/month	捺印/markings	月/month	捺印/markings
	1月/JAN	1	7月/JUL	7
	2月/FEB	2	8月/AUG	8
	3月/MAR	3	9月/SEP	9
	4月/APR	4	10月/OCT	J
	5月/MAY	5	11月/NOV	K
	6月/JUN	6	12月/DEC	L
⑦	生産日/Production day			
	日/day	捺印/markings	日/day	捺印/markings
	1	1	16	G
	2	2	17	H
	3	3	18	J
	4	4	19	K
	5	5	20	L
	6	6	21	M
	7	7	22	N
	8	8	23	P
	9	9	24	R
	10	A	25	S
	11	B	26	T
	12	C	27	U
	13	D	28	V
	14	E	29	W
	15	F	30	X
		31	Y	





## CONDITION FOR PACKAGE MOUNTING

Pb-Free recommended profile condition



This profile gives recommended values, which are not guaranteed.  
For mounting the package, evaluate the profile with the equipment, conditions, and materials to be used.

## \*Mounting by flow soldering

Flow soldering cannot be used for mounting of this package.

## \*Mounting by manual soldering

Manual soldering cannot be used for mounting of this package.

In the case of cleaning, please use cotton swab, and also please keep soldering-solution from entering into the pressure and atmospheric pressure opening. Please do not use ultrasonic cleaning (dipping).

## Cleaning method

Cleaning solution	Isopropyl alcohol
Solvent temperature	Max 45°C
Cleaning time	Within 3 min

## Note

When insert a tube to this package, please keep direction of a tube at right angle with this package.  
Also, after mounting by reflow, please make sure not to insert a tube to package before finish cooling.  
If place an extra strain on cover nozzle, it is possible that occur cover nozzle broken, interface delamination between cover nozzle and printed wiring board. It has the potential to become air-leak problem.

## Storage method

## Storage condition

Store the device under the following conditions.

Temperature: 5~30°C

Humidity: 40~70%RH

Storage life: 1year

For the product in the moisture-proof packaging, follow these conditions after unpacking.

Temperature: 5~30°C

Humidity: 40~70%RH

Storage life: 168hours

Do not store this device where a large amount of dust or harmful volatile gas exists, electrostatic is easily charged, condensation is generated, or changes in temperature and humidity are wide, or under the direct sunlight.

## Baking

If the storage time specified above has passed, mounting by soldering may cause cracks on the moistureabsorbed package. Before mounting, the package should be baked under the following conditions.

Temperature: 125°C

Treating time: 16 to 24 hours

Tray is not heat-resistant type.

Before baking, the device should be placed in a heat-resistant container.

In consideration of the time-consuming baking process and the possibility of deformed terminal, the device should be mounted promptly within the time observing the storage conditions.

If a long-term storage is needed, a desiccator or a dry box should be used.

## Handling instructions

Shipping boxes must be handled with care because any drop or shock may damage the device.

Additionally, the device must be handled in the place with the protection against electrostatic charge and without extreme changes of temperature/humidity.

## LINEUP

Rank	Range	Status
C02	-20 ~ +20 cmH <sub>2</sub> O (-1.961 ~ +1.961 kPa)	Under Planning
C04	-40 ~ +40 cmH <sub>2</sub> O (-3.922 ~ +3.922 kPa)	Sample Ready
C07	-70 ~ +70 cmH <sub>2</sub> O (-6.864 ~ +6.864 kPa)	Under Planning
C10	-100 ~ +100 cmH <sub>2</sub> O (-9.806 ~ +9.806 kPa)	Under Planning

## MITSUMI ELECTRIC CO.,LTD.

Strategy Engineering Department Semiconductor Business Division

Tel: +81-46-230-3470 / <http://www.mitsumi.co.jp>

### Notes:

Any products mentioned this datasheet are subject to any modification in their appearance and others for improvements without prior notification. The details listed here are not a guarantee of the individual products at the time of ordering. When using the products, you will be asked to check their specifications.

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